TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (U-MOS IV)

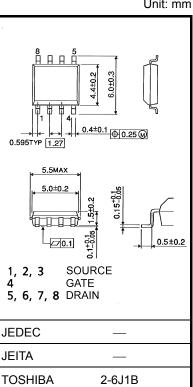
TPC8041

Lithium Ion Battery Applications Portable Equipment Applications Notebook PC Applications

- Small footprint due to small and thin package
- Low drain-source ON-resistance: R_{DS} (ON) = 5.5 m Ω (typ.)
- High forward transfer admittance: $|Y_{fs}| = 26 \text{ S}$ (typ.)
- Low leakage current: $I_{DSS} = 10 \ \mu A \ (max) \ (V_{DS} = 30 \ V)$
- Enhancement mode: V_{th} = 1.3 to 2.5 V (V_{DS} = 10 V, I_D = 1 mA)

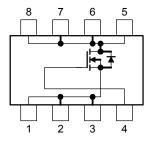
Absolute Maximum Ratings (Ta = 25°C)

Characte	ristics	Symbol	Rating	Unit
Drain-source voltage		V _{DSS}	30	V
Drain-gate voltage (R	t _{GS} = 20 kΩ)	V _{DGR}	30	V
Gate-source voltage		V _{GSS}	±20	V
Drain current	DC (Note 1)	ID	13	Α
Drain current	Pulse (Note 1)	I _{DP}	52	A
Drain power dissipati	on (t = 10 s) (Note 2a)	PD	1.9	W
Drain power dissipati	on (t = 10 s) (Note 2b)	PD	1.0	W
Single pulse avalanche energy (Note 3)		E _{AS}	44	mJ
Avalanche current		I _{AR}	13	А
Repetitive avalanche (energy Note 2a) (Note 4)	E _{AR}	0.066	mJ
Channel temperature		T _{ch}	150	°C
Storage temperature	range	T _{stg}	–55 to 150	°C



Weight: 0.08 g (typ.)

Circuit Configuration



Note: Note 1, Note 2, Note 3 and Note 4: See the next page.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in

temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

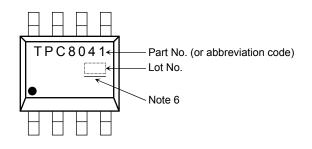
This transistor is an electrostatic-sensitive device. Please handle with caution.

Unit: mm

Thermal Characteristics

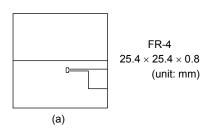
Characteristics	Symbol	Max	Unit	
Thermal resistance, channel to ambient $(t = 10 \text{ s})$ (Note 2a)	R _{th (ch-a)}	65.8	°C/W	
Thermal resistance, channel to ambient (t = 10 s) (Note 2b)	R _{th (ch-a)}	125	°C/W	

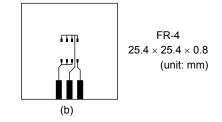
Marking (Note 5)



Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: (a) Device mounted on a glass-epoxy board (a)





(b) Device mounted on a glass-epoxy board (b)

- Note 3: $V_{DD} = 24 V$, $T_{ch} = 25^{\circ}C$ (initial), L = 0.2 mH, $I_{AR} = 13 \text{ A}$
- Note 4: Repetitive rating: pulse width limited by max channel temperature
- Note 5: on the lower left of the marking indicates Pin 1.
 - * Weekly code: (Three digits)



Week of manufacture (01 for first week of year, continuing up to 52 or 53) Year of manufacture (The last digit of the calendar year)

Note 6: A line under a Lot No. identifies the indication of product Labels. Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

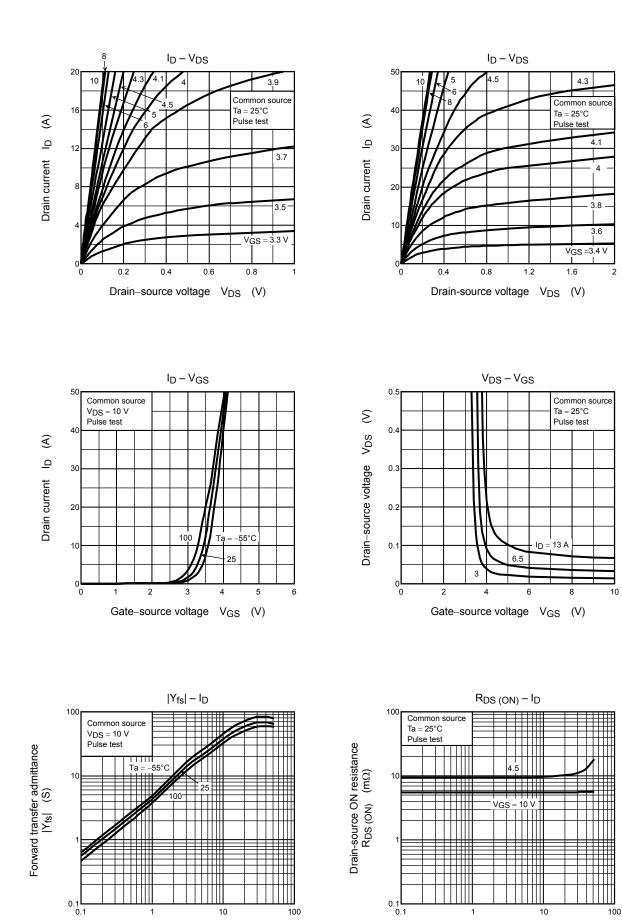
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cur	rrent	I _{GSS}	$V_{GS}=\pm 20~V,~V_{DS}=0~V$	_		±100	nA
Drain cut-OFF current		I _{DSS}	$V_{DS} = 30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	_		10	μA
Drain-source breakdown voltage		V (BR) DSS	$I_{D} = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	30		_	V
Drain-source brea	akdown vollage	V (BR) DSX	$I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$	10		_	v
Gate threshold vo	oltage	V _{th}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$	1.3		2.5	V
Drain-source ON-resistance			$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 6.5 \text{ A}$		9	13.5	- mΩ
		R _{DS (ON)}	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 6.5 \text{ A}$		5.5	7	
Forward transfer admittance		Y _{fs}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 6.5 \text{ A}$	13	26	_	S
Input capacitance		C _{iss}	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz		1270	_	pF
Reverse transfer capacitance		C _{rss}			240	_	
Output capacitance		C _{oss}		_	380	_	
Switching time	Rise time	tr	$V_{GS} \begin{array}{c} 10 \text{ V} \\ 0 \text{ V} \end{array} \begin{array}{c} I_{D} = 6.5 \text{ A} \\ 0 \text{ V} \\ 0 \text{ V} \end{array} \begin{array}{c} 0 \text{ V} \\ 0 \text{ V} \\ 0 \text{ V} \end{array} \begin{array}{c} 0 \text{ V} \\ 0 \text{ V} \\ 0 \text{ V} \\ 0 \text{ V} \end{array} \begin{array}{c} 0 \text{ V} \\ 0 \text{ V} \\ 0 \text{ V} \\ 0 \text{ V} \\ 0 \text{ V} \end{array} \begin{array}{c} 0 \text{ V} \\ 0 \text{ V} \\ 0 \text{ V} \\ 0 \text{ V} \\ 0 \text{ V} \end{array} \begin{array}{c} 0 \text{ V} \\ 0 \text{ V} \\ 0 \text{ V} \\ 0 \text{ V} \end{array} \begin{array}{c} 0 \text{ V} \\ 0 \text{ V} \\ 0 \text{ V} \\ 0 \text{ V} \end{array} $		11	_	- ns
	Turn-ON time	t _{on}		_	20	_	
	Fall time	t _f		_	15	_	
	Turn-OFF time	t _{off}		_	39	_	
Total gate charge (gate-source plus gate-drain)		Qg			27		nC
Gate-source charge 1		Q _{gs1}	$V_{DD} \approx 24 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 13 \text{ A}$		4.2		
Gate-drain ("miller") charge		Q _{gd}			8.2	—	

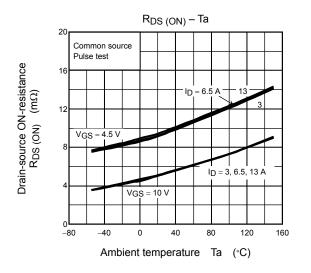
Source-Drain Ratings and Characteristics (Ta = 25°C)

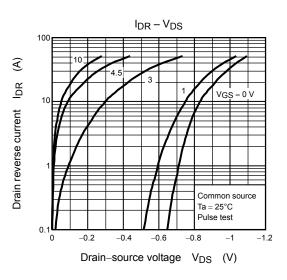
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit	
Drain reverse current	Pulse	(Note 1)	I _{DRP}	—	_	_	52	А
Forward voltage (diode)			V _{DSF}	I _{DR} = 13 A, V _{GS} = 0 V			-1.2	V

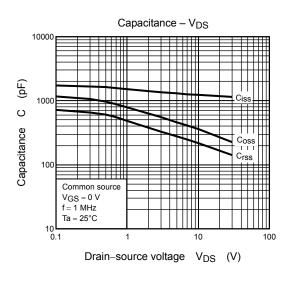


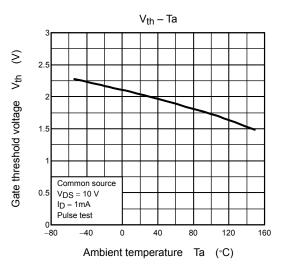
Drain current I_D (A)

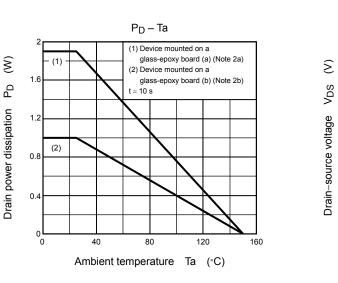
Drain current ID (A)

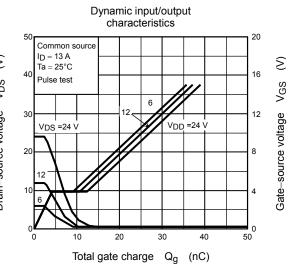


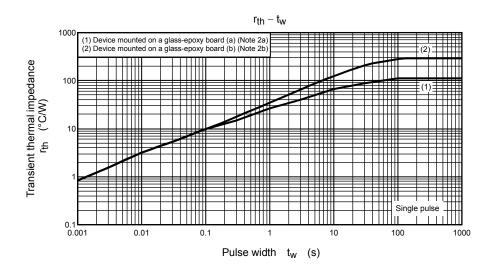


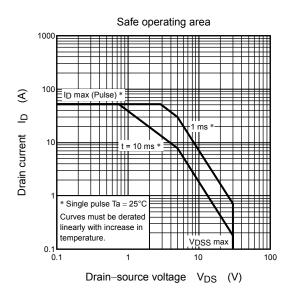












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